SPICE Device Model Si2323CDS



Vishay Siliconix

P-Channel 20 V (D-S) MOSFET

DESCRIPTION

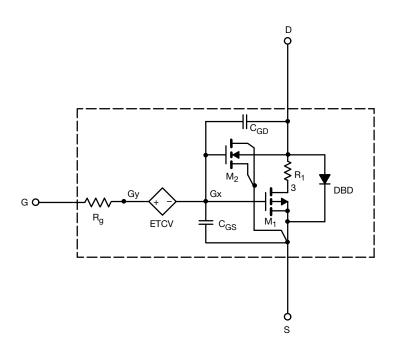
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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| SPECIFICATIONS (T _J = 25 °C, unless otherwise noted) | | | | | |
|--|---------------------|---|-------------------|------------------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | SIMULATED DATA | MEASURED DATA | UNIT |
| Static | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}, I_D = -250 \ \mu A$ | 0.75 | - | V |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V_{GS} = -4.5 V, I_D = -4.6 A | 0.032 | 0.032 | Ω |
| | | V _{GS} = -2.5 V, I _D = -4.1 A | 0.039 | 0.041 | |
| Forward Transconductance ^a | 9 _{fs} | $V_{DS} = -5 \text{ V}, \text{ I}_{D} = -4.6 \text{ A}$ | 18 | 20 | S |
| Diode Forward Voltage | V _{SD} | I _S = -3.7 A | -0.75 | -0.80 | V |
| Dynamic ^b | | | | | |
| Input Capacitance | C _{iss} | V_{DS} = -10 V, V_{GS} = 0 V, f = 1 MHz | 1080 | 1090 | pF |
| Output Capacitance | C _{oss} | | 157 | 155 | |
| Reverse Transfer Capacitance | C _{rss} | | 136 | 135 | |
| Total Gate Charge | Qg | $V_{DS} = -10 \text{ V}, \text{ V}_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -4.6 \text{ A}$ | 12 | 16 | nC |
| | | V_{DS} = -10 V, V_{GS} = -2.5 V, I_D = -4.6 A | 7.7 | 9 | |
| Gate-Source Charge | Q _{gs} | | 2.5 | 2.5 | |
| Gate-Drain Charge | Q _{gd} | | 3.2 | 3.2 | |

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

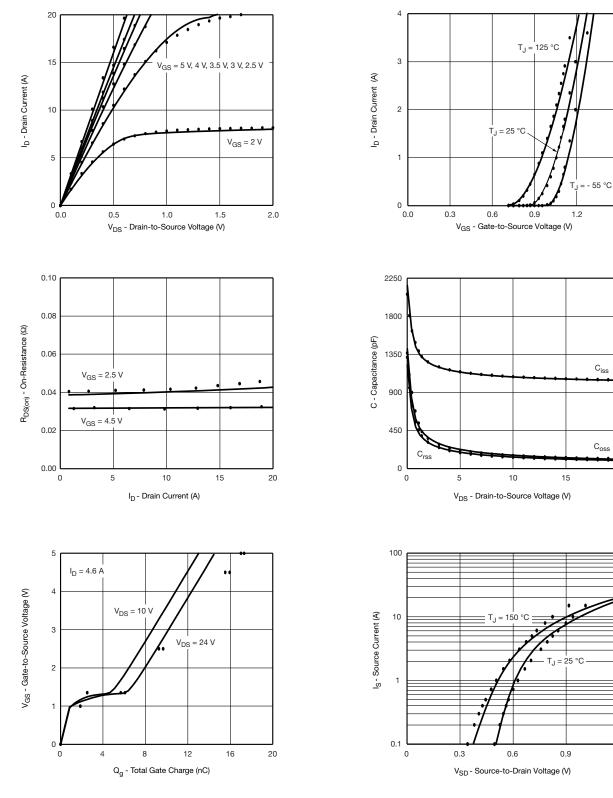


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COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)



Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

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